Code No:151AE

JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY, HYDERABAD

B. Tech I Year I Semester Examinations, December - 2018 APPLIED PHYSICS

(Common to ECE, EIE)

Max. Marks: 75 Time: 3 hours

Note: This question paper contains two parts A and B. Part A is compulsory which carries 25 marks. Answer all questions in Part A. Part B consists of 5 Units. Answer any one full question from each unit. Each question carries 10 marks and may have a, b, c as sub questions.

PART - A (25 Marks) [2] State the principle of uncertainty. [2] 1.a) What is reverse saturation current? [2] b) Write any two characteristics of PIN photodiode. c) How laser beam achieves coherence? [2] Why susceptibility of diamagnetic materials is negative. [3] What is a blackbody? State Planck's hypothesis. [3] Explain Fermi level dependence on carrier concentration. n A light emitting diode is made of GaAsP having a band gap of 1.9 eV. Determine the g) h) wavelength of the radiation emitted. Differentiate graded index fibres from step index fibres. Write a short note on piezoelectric materials.

PART-B

(50 Marks)

- Derive one-dimensional time-independent Schrodinger wave equation for an electron. Calculate the velocity and kinetic energy of an electron of wavelength 1.66 Å. 2.a) b) OR Explain Compton effect and derive expression for Compton shift. 3.a)
 - X-ray photon wavelength 0.3 Å is scattered through an angle 45° by a loosely bound b) electron. Find the wavelength of scattered photon.
- With the help of schematic diagram, explain construction and principle of operation of 4.a) bipolar junction transistor. Discuss any three applications of Hall effect.
- X -/ X = - \rightarrow OR With neat plots describe V-I characteristics of a Zener diode in both biasing conditions.
- Explain the formation of potential barrier across the p-n junction. 5.a)

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b)	- 1: -tim machanism in semiconductors.	-27.00
7.a)	Explain recombination mechanism in some construction and working of solar cell. State few	EME.
b)	disadvantages of solar cell. With relevant plots, explain V-I characteristics of a solar cell. [7+3]	
8.a)		
b)	significance. Explain the applications of lasers in medicine. [743]	geneg
9.a)	Derive an expression for acceptance angle for an optical fibre. How is it related to	
b)	numerical aperture?	
10.8	 a) Explain the term internal field. Derive an expression for internal field in the case of one dimensional array of atoms in dielectric solids. b) Deduce Claussius-Mossotti relation for dielectrics. [7+3] 	
	OR a) Classify the magnetic materials based on atomic point of view. b) State and explain Ampere's circuital law. [7+3]	
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